



# RF AMPLIFIER PENTODE

# 5590

401 A

Especially designed for use at low supply voltages. At a Plate and Grid No 2 voltage of only 45 volts the transconductance is 1900 micromhos at a grid bias of approx. — 1.5 volt. Operation range extends from low to very high frequencies.

### COLD CAPACITANCES (external shield connected to cathode)

Grid No 1 to Plate . . . . .	max. .02	$\mu\mu\text{F}$
Input . . . . .	3.4	$\mu\mu\text{F}$
Output . . . . .	2.9	$\mu\mu\text{F}$

### ABSOLUTE MAXIMUM RATINGS

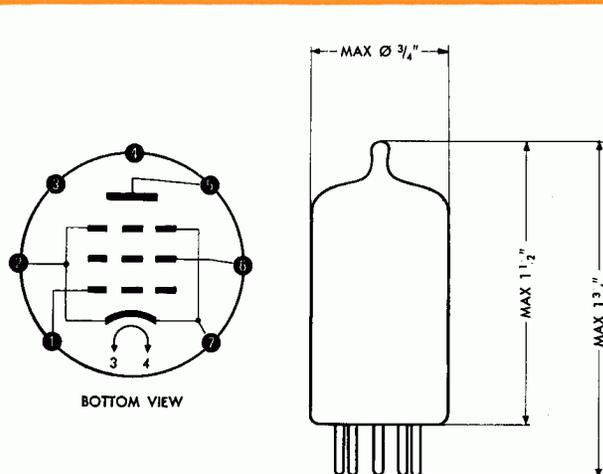
Plate Voltage . . . . .	200	volts
Grid No 2 Voltage . . . . .	155	volts
Grid No 1 Voltage, positive value . . . . .	+ 5	volts
Grid No 1 Voltage, negative value . . . . .	— 50	volts
Cathode Current . . . . .	20	ma
Plate Dissipation . . . . .	1.85	watts
Grid No 2 Dissipation (see Section A) . . . . .	.55	watt
Heater — Cathode Voltage . . . . .	100	volts
Bulb Temperature, at hottest point . . . . .	150	°C
Grid No 1 Circuit Resistance		
with fixed bias . . . . .	1.0	Mohm
with cathode bias . . . . .	2.0	Mohms

### MECHANICAL DATA

Base: Small Button Miniature 7-pin,  
RETMA E7-1  
Bulb: EIA T 5 1/2  
Mounting Position: Any

#### PIN NO. CONNECTED TO

1. Grid No 1
2. Cathode, Grid No 3,  
Int. Shield
3. Heater
4. Heater
5. Plate
6. Grid No 2
7. Cathode, Grid No 3,  
Int. Shield



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### TYPICAL OPERATION. CLASS A<sub>1</sub>

Heater Voltage . . . . .	6.3	6.3	6.3	volts
Heater Current . . . . .	.15	.15	.15	amp
Plate Supply Voltage . . . . .	45	90	120	volts
Grid No 2 Supply Voltage . . . . .	45	90	120	volts
Cathode Bias Resistor . . . . .	390	820	1000	ohms
Plate Current . . . . .	2.7	3.9	5.0	ma
Grid No 2 Current . . . . .	.8	1.2	1.5	ma
Transconductance . . . . .	1900	2000	2200	$\mu$ mhos
Plate Resistance . . . . .	.3	.45	.5	Mohm
Grid No 1 Voltage for Plate Current = 10 $\mu$ a	- 5	- 10	- 14	volts

### OPERATION RANGE VALUES

	MIN	AVE	MAX	
Heater Voltage . . . . .		6.3		volts
Plate Supply Voltage . . . . .		90		volts
Grid No 2 Supply Voltage . . . . .		90		volts
Cathode Bias Resistor . . . . .		820		ohms
Heater Current . . . . .	135	150	165	ma
Plate Current . . . . .	2.5	3.9	5.5	ma
Grid No 2 Current . . . . .		1.2	2.0	ma
Transconductance . . . . .	1500	2000	2500	$\mu$ mhos
Transconductance, End of Life Point . . . . .	1300			$\mu$ mhos
$I_{hk}$ at $E_{hk} = \pm 100$ volts . . . . .			20	$\mu$ a
Grid No 1 Current . . . . .			-1	$\mu$ a
Cutoff Plate Current at $E_{c1} = - 15$ volts . . . . .			50	$\mu$ a
<b>Vibration Output</b> . . . . .		10		mv
Measured at 2.5 g and 25 cps. $E_f = 6.3$ v, $E_{bb} = 90$ v, $E_{cc2} = 90$ v, $R_k = 820$ ohms, $C_k = 2000$ $\mu$ F, $r_p = 2000$ ohms.				



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## AVERAGE CHARACTERISTICS

